Transfer matrix method for optics in graphene layers

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A transfer matrix method is developed for optical calculations of non-interacting graphene layers. Within the framework of this method, optical properties such as reflection, transmission and absorption for single-, double- and multi-layer graphene are studied. We also apply the method to structures consisting of periodically arranged graphene layers, revealing well-defined photonic band structures and even photonic bandgaps. Finally, we discuss graphene plasmons and introduce a simple way to tune the plasmon dispersion.

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I. INTRODUCTION

Graphene is a flat monolayer of graphite with carbon atoms closely packed in a two-dimensional honeycomb lattice. A hallmark of graphene is the existence of Dirac cones in the electronic band structure, resulting in extraordinary structural and electronic properties with great potential for nanoelectronics [1–3].

In addition to outstanding electrical, mechanical and chemical properties, graphene has interesting optical response. One of the striking optical properties of graphene is that its reflectance, transmittance and absorbance are determined by the fine structure constant [4, 5]. Despite being only one-atomic-layer thick with negligible reflection, a single free-standing graphene shows significant absorbance, universally about 2.2% in a spectral range from near-infrared to visible [4, 6, 7]. In the infrared regime, graphene absorption can be altered by applying gate voltages [8, 9]. For few-layer graphene, the optical absorption is proportional to the number of layers [10], leading to a visual image contrast which can be used practically to identify the number of graphene layers on a substrate. The highly transparent and outstanding electrical properties of graphene make it attractive as transparent electrodes [11, 12]. The broadband absorption implies that graphene has the potential as an active medium used in broadband photodetectors [13, 14], ultra-fast lasers [15] and optical modulations [16].

In doped or gated graphene, collective excitations—plasmons exist with interesting optical features such as deep subwavelength and high confinement of optical fields [17, 23], similar to surface plasmons in metal surfaces [24–26]. As a result, graphene may serve as a one-atom-thick platform for infrared and terahertz metamaterials [27, 28]. A number of photonic devices such as waveguides, splitters and combiners and superlenses could be envisioned [28, 29]. Numerical simulations suggest that periodically patterned arrays of doped graphene nanodisks may completely absorb infrared light at certain resonant wavelengths [30], which was soon confirmed experimentally [31]. These interesting optical properties of graphene may also offer potential applications in photonics [32].

In this paper, we develop a transfer matrix method for studying optical properties in non-interacting graphene layers. This paper is organized as follows. In section II, we introduce the transfer matrix method for studying the propagation of light through graphene layers, together with the optical conductivity of graphene used in our calculations. In Secs. III to V, we apply the transfer matrix method to the study of optics in graphene layers. Specifically, in section III we discuss reflection, transmission and absorption in single-, double- and multi-layer graphene. In section IV we discuss photonic band structures in periodical graphene layers. In section V we discuss plasmons in graphene. Finally, we present our summary in section VI.

II. GENERAL FORMULATION

Transfer matrix method is a powerful tool in the analysis of light propagations through layered dielectric media [33, 34]. The central idea lies that electric or magnetic fields in one position can be related to those in other positions through a transfer matrix. Within the framework of the transfer matrix method, there are two kinds of matrices: one is the transmission matrix that connects the fields across an interface and the other is the propagation matrix that connects the fields propagating over a distance within a homogeneous medium.

A. Transmission matrix

We first consider the propagation of light across an interface formed by a graphene layer which separates two dielectrics of dielectric constants $\varepsilon_1$ and $\varepsilon_2$, as shown schematically in figure IV.1a. The graphene layer has an optical conductivity $\sigma$ lying at $z = 0$. Light is assumed to be polarized in the $y$ direction and propagate in the $z$ direction. For structures considered, $s$ and $p$ polarizations can be decoupled. As a result, we can deal with $s$
where

\[ \eta_p = \frac{\varepsilon_1 k_{2z}}{\varepsilon_2 k_{1z}}, \quad \xi_p = \frac{\sigma k_{2z}}{\varepsilon_0 \varepsilon_2 \omega} \]

(10)

For \( s \) polarization, the electric field is polarized along the \( y \) direction. Similarly, by applying the boundary conditions and Ohm’s law, the transmission matrix for \( s \) polarization that relates the electric fields at the two sides of the interface can be obtained, as

\[
D_{1\rightarrow 2} = \frac{1}{2} \begin{bmatrix}
1 + \eta_s + \xi_s & 1 - \eta_s + \xi_s \\
1 - \eta_s - \xi_s & 1 + \eta_s - \xi_s
\end{bmatrix},
\]

(11)

with the parameters \( \eta_s \) and \( \xi_s \) given by

\[
\eta_s = \frac{k_{2z}}{k_{1z}}, \quad \xi_s = \frac{\sigma \mu_0 \omega}{k_{1z}},
\]

(12)

where \( \mu_0 \) is the vacuum permeability.

The transmission matrix for \( s \) and \( p \) polarizations across an interface has similar forms except for the sign of \( \xi \) in the off-diagonal elements. Introducing a polarization dependent parameter \( s_m \), the transmission matrix for both polarizations can have an identical form

\[
D_{1\rightarrow 2,m} = \frac{1}{2} \begin{bmatrix}
1 + \eta_m + \xi_m & 1 - \eta_m - s_m \xi_m \\
1 - \eta_m + s_m \xi_m & 1 + \eta_m - \xi_m
\end{bmatrix},
\]

(13)

where \( m = (s, p) \) and \( \zeta_p = 1 \) and \( \zeta_s = -1 \).

### B. Propagation matrix

We now consider the propagation of light in a homogeneous medium. It can be shown that the electric or magnetic fields at \( z + \Delta z \) can be related to those at the \( z \) position by a \( 2 \times 2 \) propagation matrix

\[
P(\Delta z) = \begin{bmatrix}
e^{-i k_s \Delta z} & 0 \\
0 & e^{i k_s \Delta z}
\end{bmatrix}.
\]

(14)

### C. Transfer matrix for multi-layer graphene

For a stack of \( N \) graphene layers shown in figure (b), the transfer matrix can be obtained by transmission matrices across different interfaces and propagation matrices in different homogeneous dielectric media. Denote the field coefficients on the left side of the leftmost graphene layer by \( a_1 \) and \( b_1 \) and those on the right side of the rightmost graphene layer by \( a_{N+1} \) and \( b_{N+1} \). The two sets of field coefficients are then related by a \( 2 \times 2 \) transfer matrix \( \mathcal{M} \), namely

\[
\begin{bmatrix}
a_1 \\
b_1
\end{bmatrix} = \mathcal{M} \begin{bmatrix}
a_{N+1} \\
b_{N+1}
\end{bmatrix},
\]

(15)

with

\[
\mathcal{M} = D_{1\rightarrow 2} P(d_{1,2}) D_{2\rightarrow 3} P(d_{2,3}) \cdots P(d_{N-1,N}) D_{N\rightarrow N+1}.
\]

(16)
D. Optical conductivity of graphene

With the transfer matrix, we can easily calculate the optical spectra such as reflection, transmission and absorption for multi-layer graphene. Suppose that light is incident from left upon the multi-layer graphene with the reflection and transmission coefficients denoted respectively by $r$ and $t$. It can be shown that these coefficients are given by the elements of $M$

$$r = \frac{M_{21}}{M_{11}},$$
$$t = \frac{1}{M_{11}}.$$  \hspace{1cm} (17)

And reflectance and transmittance can be calculated for both $s$ and $p$ polarizations as

$$R_{s,p} = |r_{s,p}|^2,$$  \hspace{1cm} (19)
$$T_{s,p} = \eta_{s,p}|t_{s,p}|^2,$$  \hspace{1cm} (20)

where

$$\eta_s = k_{s(N+1)z}/k_{1z}, \quad \eta_p = \varepsilon_1 k_{s(N+1)z}/\varepsilon_{N+1} k_{1z}.$$  \hspace{1cm} (21)

Absorbance can then be readily obtained from

$$A = 1 - R - T.$$  \hspace{1cm} (22)

E. Optical conductivity of graphene

For illustration and simplicity, in the present work we only consider the situation where the chemical potential of graphene $\mu$ is much larger than the temperature. In this situation, within the random-phase approximation the optical conductivity of graphene $\sigma(\omega)$ is given by [17–19, 36–38]

$$\frac{\sigma(\Omega)}{\varepsilon_0 c} = 4\alpha \frac{i}{\Omega} + \pi\alpha \left[ \theta(\Omega - 2) + \frac{i}{\pi} \ln \left| \frac{\Omega - 2}{\Omega + 2} \right| \right].$$  \hspace{1cm} (23)

Here, $\Omega = \hbar \omega/\mu$ is the dimensionless frequency, $\alpha = e^2/4\pi\varepsilon_0 hc$ ($\sim 1/137$) is the fine structure constant and $\theta(x)$ is the Heaviside step function. The first and second terms on the right side stem from the intraband and interband contributions, respectively.

III. REFLECTION, TRANSMISSION AND ABSORPTION

A. Single-layer graphene

For a single graphene layer surrounded by two dielectrics of dielectric constants $\varepsilon_1$ and $\varepsilon_2$, suppose that light is incident from the dielectric medium of $\varepsilon_1$. The transfer matrix is no other than the transmission matrix across the interface, given by equations [9] and [11]

\begin{align*}
R_s &= \left| \frac{\sqrt{\varepsilon_1} \cos \theta_1 - \sqrt{\varepsilon_2} \cos \theta_2 - \tilde{\sigma}}{\sqrt{\varepsilon_1} \cos \theta_1 + \sqrt{\varepsilon_2} \cos \theta_2 + \tilde{\sigma}} \right|^2, \quad (24) \\
R_p &= \left| \frac{\sqrt{\varepsilon_2}}{\sqrt{\varepsilon_1} \cos \theta_2 + \sqrt{\varepsilon_2} \cos \theta_1 + \tilde{\sigma}} \right|^2, \quad (25) \\
T_s &= \left| \frac{\sqrt{\varepsilon_1} \cos \theta_1 + \sqrt{\varepsilon_2} \cos \theta_2 + \tilde{\sigma}}{\sqrt{\varepsilon_2} \cos \theta_2 + \sqrt{\varepsilon_1} \cos \theta_1 + \tilde{\sigma}} \right|^2, \quad (26) \\
T_p &= \left| \frac{\sqrt{\varepsilon_1} \cos \theta_1 + \sqrt{\varepsilon_2} \cos \theta_2 + \tilde{\sigma}}{\sqrt{\varepsilon_2} \cos \theta_2 + \sqrt{\varepsilon_1} \cos \theta_1 + \tilde{\sigma}} \right|^2. \quad (27)
\end{align*}

where $\theta_1$ and $\theta_2$ are incident and refracted angles, respectively and $\tilde{\sigma} = \sigma/\varepsilon_0 c$. By neglecting the higher-order terms of $\tilde{\sigma}$, the absorbance is given by

\begin{align*}
A_s &= \frac{4\sqrt{\varepsilon_1} \cos \theta_1 \text{Re}(\tilde{\sigma})}{(\sqrt{\varepsilon_1} \cos \theta_1 + \sqrt{\varepsilon_2} \cos \theta_2 + \tilde{\sigma})^2}, \quad (28) \\
A_p &= \frac{4\sqrt{\varepsilon_1} \text{Re}(\tilde{\sigma})}{(\sqrt{\varepsilon_2} \cos \theta_2 + \sqrt{\varepsilon_1} \cos \theta_1 + \tilde{\sigma})^2}. \quad (29)
\end{align*}

Obviously, for a single free-standing graphene layer under normal incidence its absorbance for $\Omega > 2$ is given by $\pi\alpha/(1 + \pi\alpha/2)^2 \sim \pi\alpha$.

In figure 2, the reflectance, transmittance and absorbance at different incident angles for single graphene are shown. Light is incident from the dielectric of $\varepsilon_1$. Reflection and transmission are altered somewhat with re-
spect to the case without the graphene layer. For \( \varepsilon_1 \leq \varepsilon_2 \), the absorbance decreases monotonically with increasing incident angle for \( p \) polarization, while for \( s \) polarization it increases up to a maximum and then decreases monotonically. For \( \varepsilon_1 = \varepsilon_2 \), the absorbance for \( s \) polarization takes a universal value at normal incidence, about \( \pi\alpha \) and the maximal absorbance is 0.5 at an incident angle very close to \( \pi/2 \).

For \( \varepsilon_1 > \varepsilon_2 \), total internal reflection is expected. With the presence of the graphene layer, there is nearly no change in the critical angle. However, above the critical angle reflectance is no longer total (smaller than one). For \( s \) polarization, the absorbance around the critical angle is several times larger than the universal value of \( \pi\alpha \). This implies that the configuration of total internal reflection could be exploited in measurements of optical conductivity of graphene since it can suppress the signal-to-noise ratio considerably.

### B. Double-layer graphene

Consider two graphene layers which are separated by a dielectric of \( \varepsilon_2 \) with a thickness of \( d \). The dielectric constant of the leftmost dielectric is \( \varepsilon_1 \) and that of the rightmost dielectric is \( \varepsilon_3 \). The transfer matrix of the structure can be obtained from equation (16) as

\[
\mathcal{M} = D_{1\rightarrow 2} P(d) D_{2\rightarrow 3},
\]

whose elements are given by

\[
M_{\mu
u,m} = \frac{\cos k_z d}{2} A_{\mu
u,m} + \frac{i \sin k_z d}{2} B_{\mu
u,m},
\]

where \( \mu = 1, 2 \) and \( \nu = 1, 2 \). The parameters \( A_{\mu
u,m} \) and \( B_{\mu
u,m} \) are given by

\[
A_{\mu
u,m} = 1 + (-1)^{\mu+\nu} \eta_m \eta'_m - (-1)^{\nu} (\xi'_m + s_m \xi_m \eta'_m),
\]

\[
B_{\mu
u,m} = (-1)^{\mu} \eta_m + (-1)^{\nu} (\eta'_m + s_m \xi_m \eta'_m) - (-1)^{\nu+\mu} \eta_m \xi'_m - s_m \xi_m,
\]

where

\[
\eta = k_{2z}/k_{1z}, \quad \eta_p = \varepsilon_1 k_{2z}/\varepsilon_2 k_{1z},
\]

\[
\xi = \sigma \mu_0 \omega/k_{1z}, \quad \xi_p = k_{2z}/\varepsilon_2 \varepsilon_0 \omega,
\]

\[
\eta = k_{3z}/k_{2z}, \quad \eta_p = \varepsilon k_{3z}/\varepsilon_2 \varepsilon_0 \omega,
\]

\[
\xi = \sigma \mu_0 \omega/k_{2z}, \quad \xi_p = k_{3z}/\varepsilon_2 \varepsilon_0 \omega.
\]

In figure 8 the reflectance, transmittance and absorbance of double-layer graphene for \( \varepsilon_1 = \varepsilon_3 = 1 \) and \( \varepsilon_2 = 2.25 \) are shown. For small \( d \), despite different values, the dependence of the reflectance, transmittance and absorbance on the incident angle is, in general, similar to that of single-layer graphene. At normal incidence, the absorbance is nearly twice the universal value of \( \pi\alpha \). For large \( d \), however, there are oscillations in reflectance, transmittance and absorbance, which originate from the thin-film interference.

### C. Multi-layer graphene

For multi-layer graphene, the transfer matrix can be obtained from equation (16). Reflectance, transmittance and absorbance can be then obtained from equations (19), (20) and (22) respectively.

In figure 9 the reflectance and absorbance of multi-layer graphene at normal incidence are shown. The structure consists of identical graphene layers in air, separated equally by a distance \( d \). At low frequencies the reflectance is close to one up to a certain cutoff frequency. Above the cutoff frequency, for small \( d \) the reflectance oscillates and drops rapidly to zero. For large \( d \), however, there appear sharp reflection peaks for frequency above the cutoff frequency, resulting from the multiple interference by the graphene layers.

The structure has zero absorbance for \( \Omega < 2 \) and shows remarkable absorption for \( \Omega > 2 \). For small \( d \), the absorbance is nearly a constant, being 0.5 for \( \Omega > 2 \). With increasing \( d \), multiple interference by graphene layers may play an important role, leading to sharp absorption dips. These interesting properties imply that multi-layer graphene has the potential as dark materials for achieving lower reflection coatings and enhanced photodetection.

![FIG. 3.](image-url) Reflectance, transmittance and absorbance of double-layer graphene as a function of the incident angle for \( \Omega > 2 \). Two graphene layers have the same optical conductivity. (a) Reflectance and transmittance for \( s \) and \( p \) polarizations with \( d = 0.1hc/\mu \) (corresponding to 0.132 \( \mu \) for a typical chemical potential \( \mu = 0.15 \) eV). Dashed lines represent those in the absence of the graphene layers. The corresponding absorbance is given in (b). (c) Same as (a) but for \( d = 8hc/\mu \) (corresponding to 10.5 \( \mu \) for \( \mu = 0.15 \) eV). The corresponding absorbance is given in (d).
IV. PHOTONIC BAND STRUCTURE OF PERIODICAL GRAPHENE LAYERS

When dielectrics are arranged in a periodical way to form so-called photonic crystals [11–12], electromagnetic waves should be strongly modulated by Bragg scatterings, showing photonic band structures with well-defined photonic bands and even photonic bandgaps. For graphene layers stacking in a periodical way, photonic band structures should also be expected due to the introduced periodical modulations.

The first structure considered is shown schematically in figure 5(a). It is composed of identical graphene layers embedded into the interfaces of a one-dimensional photonic crystal consisting of two dielectrics of \( \varepsilon_1 \) and \( \varepsilon_2 \) with a thickness of \( d_1 \) and \( d_2 \), respectively. For such a structure, its transfer matrix after propagating over one unit cell reads

\[
M_m = D_{1\rightarrow2,m}P(d_2)D_{2\rightarrow1,m}P(d_1). \tag{35}
\]

The photonic band structure can be then obtained from the diagonal elements of the transfer matrix [34],

\[
\cos(qd) = (M_{11,m} + M_{22,m})/2, \quad \text{where} \quad q \text{ is the Bloch wave-vector and} \quad d = d_1 + d_2 \text{ is the lattice constant. It can be explicitly written as}
\]

\[
\cos(qd) = \cos(k_{1z}d_1) \cos(k_{2z}d_2) - \frac{1}{2} (\eta_m + \eta_m^{-1}) \times \sin(k_{1z}d_1) \sin(k_{2z}d_2) - \Delta_m, \tag{36}
\]

where

\[
\Delta_m = i\xi_m [(1 + \eta_m^{-1}) \sin(k_{1z}d_1 + k_{2z}d_2) + \varsigma_m (1 - \eta_m^{-1}) \sin(k_{1z}d_1 - k_{2z}d_2)] + \frac{\varepsilon_2^2}{2\eta_m} \sin(k_{1z}d_1) \sin(k_{2z}d_2). \tag{37}
\]

Without the term \( \Delta_m \), equation (36) reduces to the photonic band structure of a one-dimensional photonic crystal [34].

For identical graphene layers separated equally in air as shown in figure 5(b), the transfer matrix simply reads \( M_m = D_m P(d) \), where

\[
D_m = \begin{bmatrix} \frac{1 + \xi_m}{2} & -\varsigma_m \xi_m / 2 \\ \varsigma_m \xi_m / 2 & \frac{1 - \xi_m}{2} \end{bmatrix}. \tag{38}
\]

The photonic band structure of the structure is then given by

\[
\cos(qd) = \cos(k_zd) - \frac{i\xi_m}{2} \sin(k_zd), \tag{39}
\]

which is identical to that given in reference [43].

In figure 5 the photonic band structures of periodical graphene layers are shown for the propagation direction perpendicular to the graphene layers. For both
structures the first photonic band starts from a certain non-zero cutoff frequency, different from conventional dielectric photonic crystals. This cutoff frequency corresponds exactly to that observed in the reflection spectra shown in figure 4. Below the cutoff frequency, high reflection or low transmission is expected, which was also observed in numerical simulations of a stack of graphene layers separated by dielectric slabs \[14\]. It is known that in the low-frequency limit periodical metallic structures can be considered as bulk metals with a depressed effective plasma frequency \[43, 44\]. Thus, periodical graphene layers can also be regarded as a bulk metal with an extremely low effective plasma frequency.

For the structure shown in figure 5(a), the photonic crystal in the absence of graphene layers displays well-defined photonic bands and bandgaps. With the introduction of graphene layers, however, a series of mini photonic bandgaps appear owing to the multiple interference by graphene layers. It is known that for frequency within photonic bandgaps light propagation is forbidden \[40–42\]. For a structure consisting of finite graphene layers, this will cause strong reflection for frequency located into the mini photonic bandgaps, as can be clearly seen from figure 4(b).

V. PLASMONS

A flat metal surface can support surface plasmons \[24–26\] which are transverse magnetic (TM) electromagnetic waves coupled with collective oscillations of surface charges. Surface plasmons can propagate along the metal surface with the fields decaying exponentially away from the both sides of the surface. In doped or gated graphene, free carriers can also support plasmons \[17–22\]. Owing to the two-dimensional nature and unique electronic band structure, graphene can support not only TM but also transverse electric (TE) plasmons \[19\]. The later does no exist in conventional metal surfaces.

For a graphene layer surrounded by two dielectrics as shown in figure 5(a), the transfer matrix is simply the transmission matrix. From equation (17), the reflection coefficient of the system can be obtained. The condition for the existence of plasmons is that the reflection coefficient has poles, namely

\[ 1 + \eta_m + \varsigma_m \xi_m = 0, \]

where the subscript \( m \) stands for \( s \) and \( p \) polarization, corresponding to TE and TM modes, respectively.

From equation (10), the dispersion of TM plasmons can be obtained as

\[
\frac{\varepsilon_1}{\sqrt{Q^2 - \varepsilon_1 \Omega^2}} + \frac{\varepsilon_2}{\sqrt{Q^2 - \varepsilon_2 \Omega^2}} = -\frac{i\sigma(\Omega) / \varepsilon_0 c}{\Omega},
\]

with \( Q \equiv \hbar q / \mu \), where \( q \equiv k_z \) is the wave-vector of the plasmons. Obviously, TM plasmons can exist if the imaginary part of \( \sigma \) is positive. From the above equation, TM plasmons are far below the light line, i.e., \( q \gg \omega / c \).

Thus, in this non-retarded regime, the dispersion of TM plasmons is simplified to

\[
Q = - (\varepsilon_1 + \varepsilon_2) \Omega (\varepsilon_0 c / i\sigma).
\]

For \( \Omega > 2 \), \( \sigma \) has a real value as well, leading to a strong loss due to interband excitations. For small \( q \), the dispersion of TM plasmons reduces to

\[
\Omega = 2 \sqrt{\frac{\alpha}{(\varepsilon_1 + \varepsilon_2)}},
\]

which shows the known \( \sqrt{q} \)-dependence \[17, 18\].

From equation (10), the dispersion of TE plasmons is given by

\[
\sqrt{Q^2 - \varepsilon_1 \Omega^2} + \sqrt{Q^2 - \varepsilon_2 \Omega^2} = \frac{i\sigma(\Omega)}{\varepsilon_0 c},
\]

which is the same as that given in reference \[19\]. TE plasmons can exist if \( \varepsilon_1 = \varepsilon_2 \) and the imaginary part of \( \sigma \) is negative (for \( \Omega > 1.667 \)). Note that the term on the right side of the above equation is very small in the frequency window \( 1.667 < \Omega < 2 \). As a result, the dispersion of TE plasmons should be below but very close to the light line \( \omega = \sqrt{\varepsilon_0 c} \).

We now consider a structure where a graphene layer is apart from a dielectric substrate of \( \varepsilon_2 \) over a distance of \( d \), as shown schematically in the inset of figure 5. For the structure, TE plasmons do not exist for finite \( d \) and thus we only discuss TM plasmons. For \( p \) polarization, the transfer matrix of the structure can be obtained from equation (16), namely

\[
\mathcal{M} = DP(d)D',
\]

where

\[
D = \frac{1}{2} \begin{bmatrix} 1 + \eta_p + \xi_p & 1 - \eta_p - \xi_p \\ 1 - \eta_p + \xi_p & 1 + \eta_p - \xi_p \end{bmatrix},
\]

\[
D' = \frac{1}{2} \begin{bmatrix} 1 + \eta'_p & 1 - \eta'_p \\ 1 - \eta'_p & 1 + \eta'_p \end{bmatrix},
\]

\[
P = \begin{bmatrix} e^{-i k_{1z} d} & 0 \\ 0 & e^{i k_{1z} d} \end{bmatrix},
\]

with

\[
\eta_p = 1, \quad \xi_p = \sigma k_{1z} / \varepsilon_0 \varepsilon_1 \omega, \quad \eta'_p = \varepsilon_1 k_{2z} / \varepsilon_2 k_{1z}.
\]
With the transfer matrix, it is easy to obtain the reflection coefficient from equation (17). The condition for the existence of plasmons thus reads

\[
(1 + \eta_p + \xi_p) (1 + \eta_p') e^{-i k_{1z} d} + (1 - \eta_p - \xi_p) (1 - \eta_p') e^{i k_{1z} d} = 0.
\] (50)

Since the dispersion of graphene plasmons lies far below the light line, the non-retarded condition \( q \gg \omega/c \) still holds, leading to \( \eta_p' \approx \varepsilon_1 / \varepsilon_2 \) and \( \xi_p \approx i \omega / \varepsilon_0 \varepsilon_2 \). Thus, plasmon dispersion can be simplified as

\[
\frac{2 \varepsilon_1 (\varepsilon_1 + \varepsilon_2)}{(\varepsilon_1 + \varepsilon_2) + (\varepsilon_1 - \varepsilon_2) e^{-2 q d}} = -\frac{i \sigma Q}{\varepsilon_0 c \Omega}.
\] (51)

where \( d = d \mu / hc \).

In figure 6, the dispersion of TM plasmons for the structure shown in the inset is given. The separation of the graphene layer from the dielectric substrate of \( \varepsilon_2 = 10 \) over a distance of \( d \) and the other dielectrics are air with \( \varepsilon_1 = 1 \). Blue, green and red lines are the results for \( d = 0.005, 0.01 \) and \( 0.1 \), respectively. The dotted line represents the dispersion for a free-standing graphene layer in air and the dashed line corresponds to the case \( d = 0 \).

VI. CONCLUSIONS

In the present paper, we developed a transfer matrix method for optical calculations in non-interacting graphene layers. With the framework of this method, the transfer matrix for various graphene layers can be obtained. With the transfer matrix, reflectance, transmittance and absorbance spectra of graphene layers can be easily obtained. In addition, photonic band structures for periodical graphene layers and even graphene plasmons can be studied in a rather simple way.

Using the transfer matrix method, we studied the optical properties such as reflection, transmission and absorption for single-, double- and multi-layer graphene. We showed that the configuration of total internal reflection in single-layer graphene and thin-film interference effects in double-layer graphene could be exploited to enhance the light absorption. For multi-layer graphene, there exists a cutoff frequency below which the reflectance is as high as one. For a small spacing distance, the absorbance is as high as 50% for \( \Omega > 2 \). With increasing spacing distance, sharp reflection peaks and absorption dips appear owing to the multiple interference by graphene layers.

We applied the transfer matrix method to structures consisting of periodically arranged identical graphene layers. The structures are characterized by photonic band structures with well-defined photonic bands and bandgaps. We revealed that these structures can be regarded as bulk metals with an extremely low effective plasma frequency.

Finally, we discussed plasmons in a graphene layer which is apart from a dielectric substrate. We found that the plasmon dispersion can be tuned by the separating distance between the graphene layer and the dielectric substrate. Our results show that the transfer matrix method could serve as a versatile tool to study optical properties in graphene layers.
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